



# BSS138

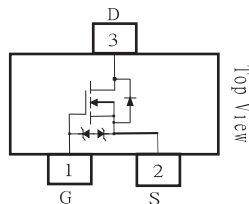
## 50V N-Channel Enhancement Mode MOSFET - ESD Protected

### FEATURES

- $R_{DS(ON)}$ ,  $V_{GS}@10V, I_{DS}@500mA=3\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V, I_{DS}@200mA=4\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@2.5V, I_{DS}@100mA=6\Omega$
- Advanced Trench Process Technology
- High Density Cell Design For Ultra Low On-Resistance
- Very Low Leakage Current In Off Condition
- Specially Designed for Battery Operated Systems, Solid-State Relays Drivers : Relays, Displays, Lamps, Solenoids, Memories, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

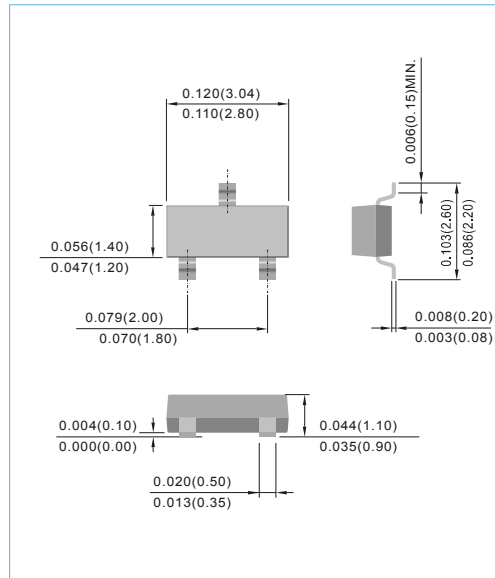
### MECHANICAL DATA

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Apprx. Weight: 0.0003 ounce, 0.0084 gram
- Marking: 138



### SOT-23

Unit : inch(mm)



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted )

PARAMETER	Symbol	Limit	Units
Drain-Source Voltage	$V_{DS}$	50	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	300	mA
Pulsed Drain Current <sup>1)</sup>	$I_{DM}$	2000	mA
Maximum Power Dissipation	$P_D$	$T_A=25^\circ\text{C}$ 350 $T_A=75^\circ\text{C}$ 210	mW
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to + 150	$^\circ\text{C}$
Junction-to Ambient Thermal Resistance(PCB mounted) <sup>2)</sup>	$R_{\theta JA}$	357	$^\circ\text{C/W}$

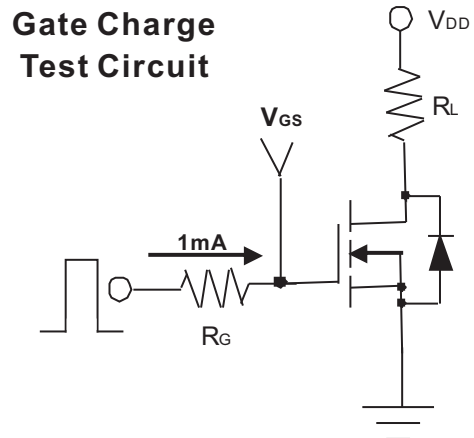
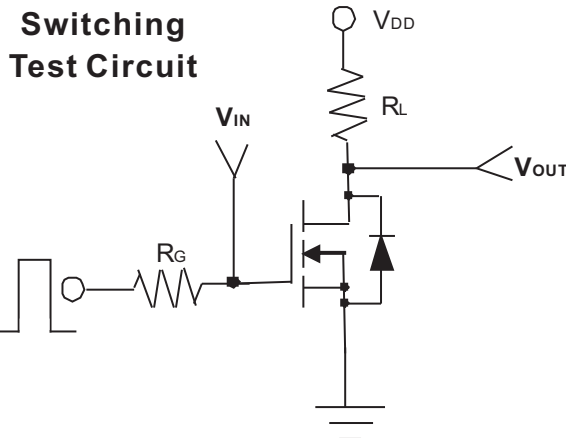
Note: 1. Maximum DC current limited by the package  
2. Surface mounted on FR4 board,  $t < 5$  sec



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## ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Units
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=10\mu A$	50	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.8	-	1.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=2.5V, I_D=100mA$	-	2.8	6.0	Ω
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=200mA$	-	1.8	4.0	
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=500mA$	-	1.6	3.0	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=50V, V_{GS}=0V$	-	-	1	μA
Gate Body Leakage	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±10	μA
Forward Transconductance	$g_{fs}$	$V_{DS}=10V, I_D=250mA$	100	-	-	mS
<b>Dynamic</b>						
Total Gate Charge	$Q_g$	$V_{DS}=25V, I_D=250mA$ $V_{GS}=4.5V$	-	-	1.0	nC
Turn-On Time	$t_{on}$	$V_{DD}=30V, R_L=100\Omega$ $I_D=300mA, V_{GEN}=10V$ $R_G=6\Omega$	-	-	40	ns
Turn-Off Time	$t_{off}$		-	-	150	
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V$ $f=1.0MHz$	-	-	50	pF
Output Capacitance	$C_{oss}$		-	-	10	
Reverse Transfer Capacitance	$C_{rss}$		-	-	5	
<b>Source-Drain Diode</b>						
Diode Forward Voltage	$V_{SD}$	$I_S=250mA, V_{GS}=0V$	-	0.82	1.2	V
Continuous Diode Forward Current	$I_S$	-	-	-	300	mA
Pulse Diode Forward Current	$I_{SM}$	-	-	-	2000	mA





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Typical Characteristics Curves ( $T_A=25^\circ\text{C}$ , unless otherwise noted)

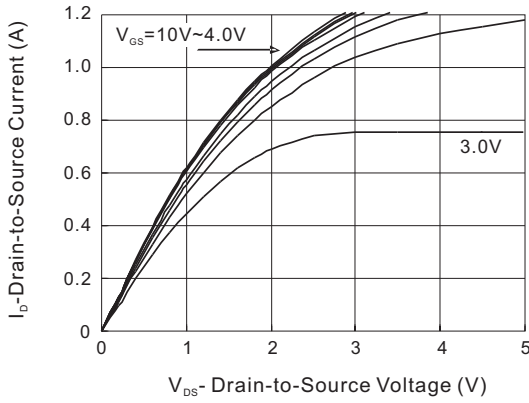


FIG.1- Output Characteristic

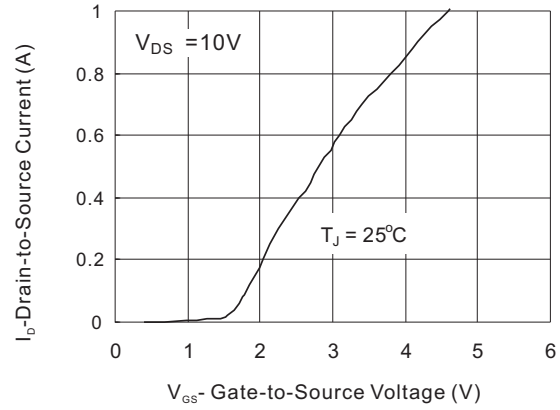


FIG.2- Transfer Characteristic

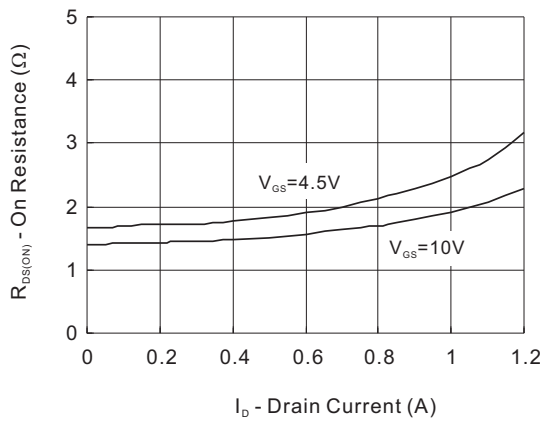


FIG.3- On Resistance vs Drain Current

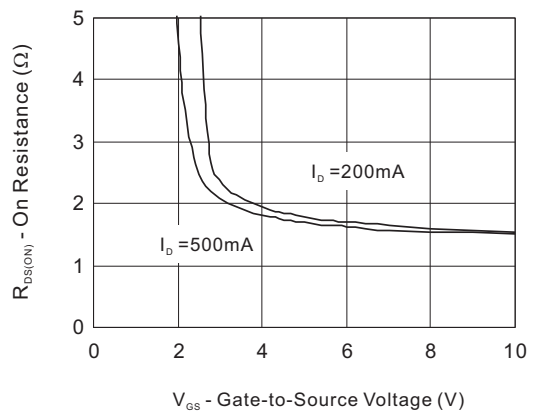


FIG.4- On Resistance vs Gate to Source Voltage

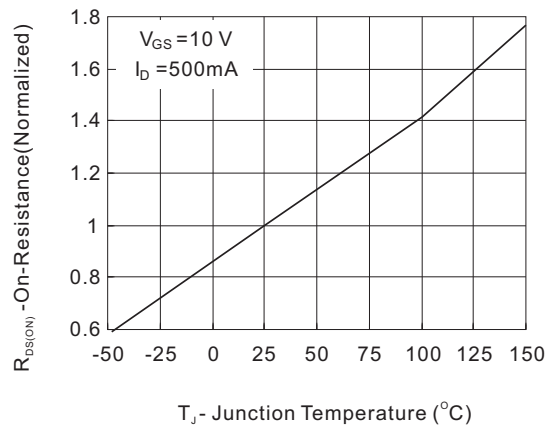
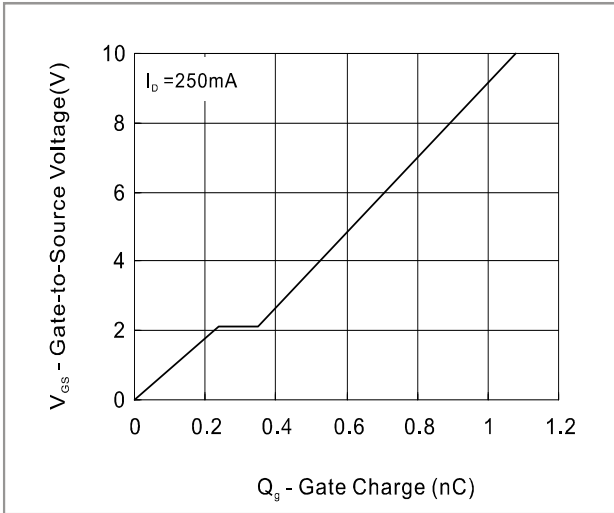


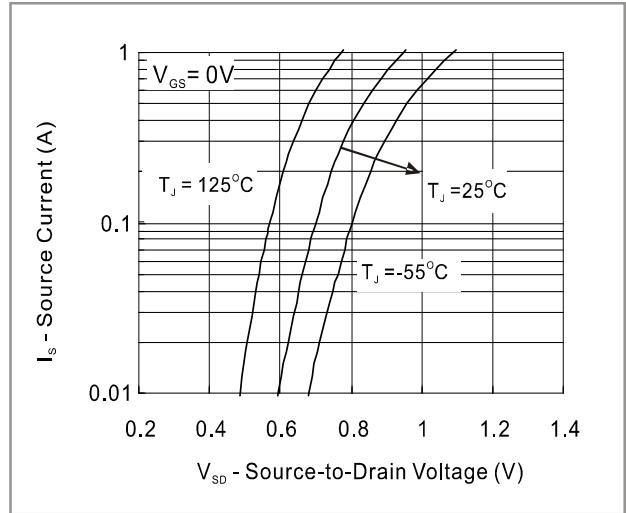
FIG.5- On Resistance vs Junction Temperature



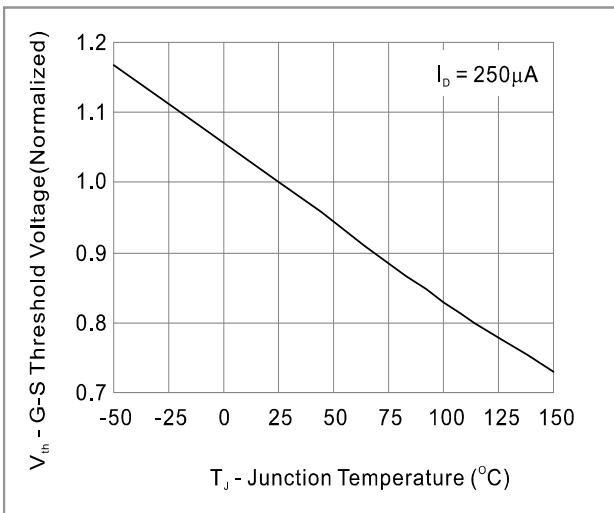
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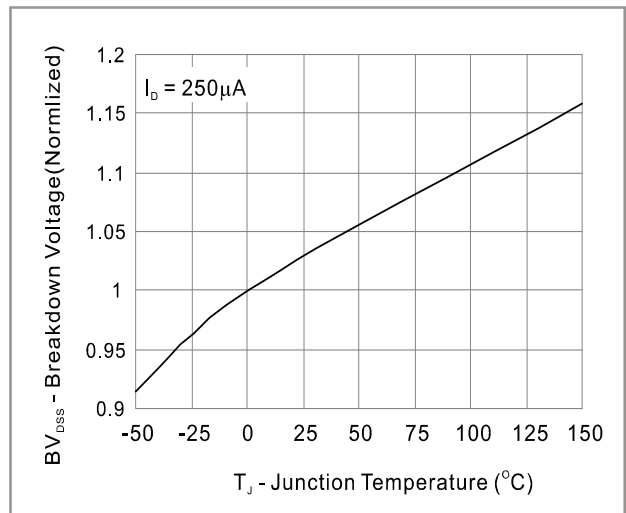
**Fig.6 - Gate Charge Waveform**



**Fig.7 Source-Drain Diode Forward Voltage**



**Fig.8 - Threshold Voltage vs Temperature**

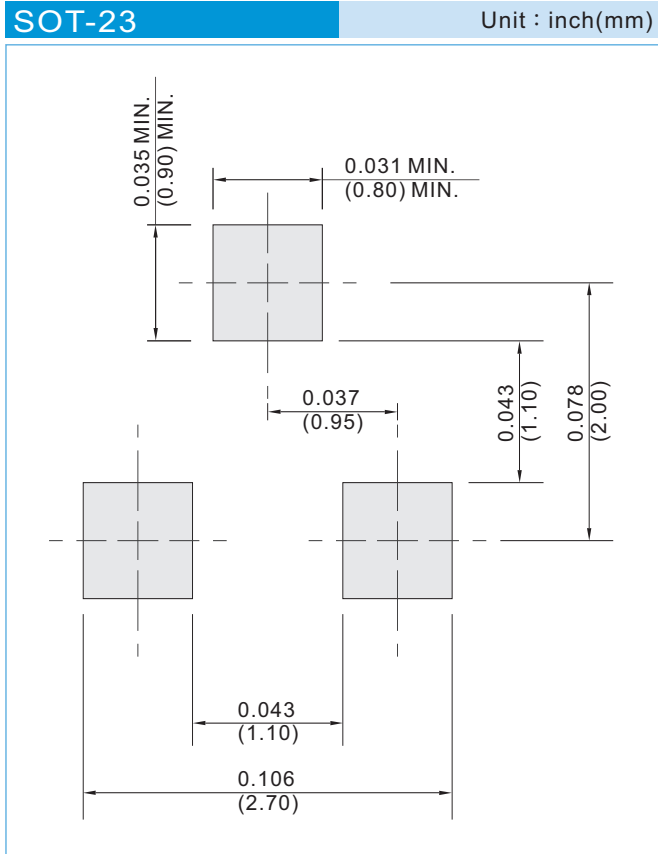


**Fig.9 - Breakdown Voltage vs Junction Temperature**



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## MOUNTING PAD LAYOUT



## ORDER INFORMATION

- Packing information
  - T/R - 12K per 13" plastic Reel
  - T/R - 3K per 7" plastic Reel



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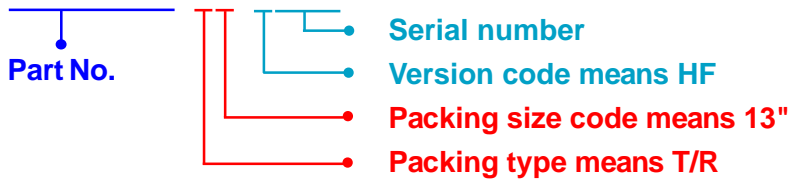
## Part No\_packing code\_Version

BSS138\_R1\_00001

BSS138\_R2\_00001

For example :

**RB500V-40\_R2\_00001**



Packing Code XX				Version Code XXXXX		
Packing type	1 <sup>st</sup> Code	Packing size code	2 <sup>nd</sup> Code	HF or RoHS	1 <sup>st</sup> Code	2 <sup>nd</sup> ~5 <sup>th</sup> Code
Tape and Ammunition Box (T/B)	A	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	B	13"	2			
Tube Packing (T/P)	T	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			



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